	REVISIONS																			
L <mark>路</mark> 询"5	L暨询"5962R8993201V2A"供应费 ^{ESCRIPTION}							DA	NTE (Y	R-MO-E	DA)		APPR	OVED						
A			accorda			<u> </u>								92-01-	09		M. A	. Frye		
В		Add RHA requirements. Add device type 02. Add case outlines E and F. Update boilerplaterrp									98-10	09		R. N	IONNIN	١				
С	Make	e chang	ges to 1.	.5, RHA	\ desigi	nators i	n table	I, and ta	able IIA	rrp				99-07	-30		R. M		١	
REV																				
SHEET																				
REV																				
SHEET																				
REV STATUS	1		1	REV	/		с	С	С	С	С	С	С	С	С	с	С	С	С	
OF SHEETS				SHE	ET		1	2	3	4	5	6	7	8	9	10	11	12	13	
PMIC N/A					PAREE K C. C) BY FFICE	R		L	DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216										
MICRO	NDAF DCIR(AWIN	CUIT			CKED HARLE		ESORE													
THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS			MICROCIRCUIT, LINEAR, RADIATION HARDENED, 8-BIT, HIGH SPEED, MULTIPLYING D/A CONVERTER, MONOLITHIC SILICON																	
				DRA		APPR()9-07	OVAL D	ATE												
AM	SC N/A	L .		REV	ISION	LEVEL	c				ZE A		GE CC 67268				5962-	8993	2	
										SHE	ET		1	OF	13					
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DSCC FORM 2233 APR 97

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

5962-E393-99

1. SCOPE

1.2 PIN. The PIN is as shown in the following examples.

For device classes M and Q: 5962 89932 01 RHA Federal Device Case Lead designator finish stock class type outline (see 1.2.1) (see 1.2.4) (see 1.2.5) designator (see 1.2.2) v Drawing number For device class V: 5962 R 89932 01 * * * * RHA Device Federal Device Case Lead outline finish stock class designator class type designator (see 1.2.1) (see 1.2.2) designator (see 1.2.4) (see 1.2.5) (see 1.2.3) v Drawing number

1.2.1 <u>RHA designator</u>. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 <u>Device type(s)</u>. The device type(s) identify the circuit function as follows:

Device type	<u>Generic number</u>	Circuit function
01	DAC08	8-bit, high-speed, multiplying D/A converter
02	DAC08A	8-bit, high-speed, multiplying D/A converter

1.2.3 <u>Device class designator</u>. The device class designator is a single letter identifying the product assurance level as listed below. Since the device class designator has been added after the original issuance of this drawing, device classes M and Q designators will not be included in the PIN and will not be marked on the device.

Device class	<u>1</u>	Device requiremen	ts documentation						
Μ		Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535 , appendix A							
Q or V	Certification and	qualification to M	IL-PRF-38535						
STANDAF MICROCIRCUIT I		SIZE A		5962-89932					
DEFENSE SUPPLY CEN COLUMBUS, OHIO			REVISION LEVEL C	SHEET 2					

1.2.4 <u>Case outline(s)</u> . The case outline(s) are as designated	in MIL-STD-1835	and as follows:	
查词"59662 Research 201 V2A的基本 designator	Terminals	Package style	
E GDIP1-T16 or CDIP2-T16	16	Dual-in-line	
F GDFP2-F16 or CDFP3-F16	16	Flat pack	
2 CQCC1-N20	20	Square leadless chip o	arrier
1.2.5 <u>Lead finish</u> . The lead finish is as specified in MIL-PRF- appendix A for device class M.	38535 for device	classes Q and V or MIL-PRF	-38535,
1.3 <u>Absolute maximum ratings</u> . <u>1</u> /			
Supply voltage (V+ to V-)		36 V dc	
Logic inputs		· · ·	δ V dc)
Logic control voltage (V_{LC})			
Analog current outputs (at V- = 15 V) Reference input (V _{REF+} to V _{REF} .)			
Reference input differential voltage (V _{REF+} to V _{REF-})			
Reference input current (IvREF+)			
Power dissipation (P_D) :			
Cases E, F, and 2			
Maximum junction temperature (TJ)			
Lead temperature (soldering, 60 seconds)			
Storage temperature			
Thermal resistance, junction-to-case (θ_{JC})		See MIL-STD-1	830
Thermal resistance, junction-to-ambient (θ _{JA}): Case E.		91°C/M	
Case F			
Case 2			
1.4 Recommended operating conditions.			
Supply voltage (V _S)		+15 \/ da	
Input reference current (I _{REF})			
Ambient operating temperature range (T_A)			2
 1.5 <u>Radiation features</u>. Maximum total dose available (dose rate = 50 – 300 rads 	(Si)/s)	100 Krads	
2. APPLICABLE DOCUMENTS			
2.1 <u>Government specification, standards, and handbooks</u> . T this drawing to the extent specified herein. Unless otherwise spe of the Department of Defense Index of Specifications and Stand	ecified, the issues	of these documents are thos	e listed in the issue
<u>1</u> / Stresses above the absolute maximum rating may cause per maximum levels may degrade performance and affect reliab		e to the device. Extended ope	eration at the
STANDARD	SIZE		1
	A		5962-89932
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000			3 SHEET
DSCC FORM 2234	Т		

SPECIFICATION

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MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883	-	Test Method Standard Microcircuits.
MIL-STD-973	-	Configuration Management.
MIL-STD-1835	-	Interface Standard For Microcircuit Case Outlines.

HANDBOOKS

DEPARTMENT OF DEFENSE

MIL-HDBK-103 - List of Standard Microcircuit Drawings (SMD's). MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.

3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

3.2.3 Radiation exposure circuit. The radiation exposure circuit shall be as specified on figure 2.

3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full ambient operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-89932
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		C	4

查询"5962R899320 ⁻						1		
Test	Symbol	Conditions <u>1</u> -55°C # T _A #+12 V _S = ±15 V, I _{REF} = 2 unless otherwise spe	5°C mA	Group A subgroups	Device type	L	imits	Unit
						Min	Max	-
Power supply <u>2</u> /	l+	$V_{\rm S} = \pm 15 \text{ V or } +5 \text{ V}, -$		1, 2, 3	All		3.8	mA
		M,D,	P,L,R	1			4	
		$V_{S} = \pm 5 \text{ V}, \text{ I}_{\text{REF}} = 1 \text{ m}$	ıΑ	1, 2, 3			3.8	
		M,D,	P,L,R	1	-		4	-
	-	$V_{\rm S} = \pm 15 \text{ V or } +5 \text{ V}, -$	-15 V	1, 2, 3	All		-7.8	mA
		M,D,	P,L,R	1			-8	-
		V _S = ±5 V, I _{REF} = 1 m	A	1, 2, 3			-5.8	-
		M,D,	P,L,R	1	-		-8	-
Full range current	I _{FR}	V _{REF} = 10 V,		1, 2, 3	01	1.94	2.04	mA
		$V_{\text{REF+}}, V_{\text{REF-}} = 5 \text{ k}\Omega$			_	1.005	0.04	_
			P,L,R	1		1.925	2.04	
		V _{REF} = 10 V, V _{REF+} , V _{REF-} = 5 kΩ		1, 2, 3	02	1.984	2	
			P,L,R	1	-	1.97	2	
Output voltage compliance	V _{oc}	Full range current change < ½ LSB <u>3</u>	/	1, 2, 3	All	-10	+18	V
Zero scale current	I _{ZS}			1, 2, 3	01		2	μA
		M,D,	P,L,R	1			2	
				1, 2, 3	02		1	
		M,D,	P,L,R	1			1	1
Full range symmetry	I _{FRS}	 I _{FR} - I _{FR} <u>3</u> /		1, 2, 3	01		±8	μA
	I'FRS			, 2, 3	01		±8 ±4	+
Output current range	I _{OR1}	$V_{\text{REF}} = 15 \text{ V}, \text{ V} = -10$		1, 2, 3	All	2.1		mA
	I _{OR2}	$V_{REF+}, V_{REF-} = 5 k\Omega$ $V_{REF} = 25 V, V_{-} = -12$		-		4.2		-
		$V_{\text{REF+}}, V_{\text{REF-}} = 5 \text{ k}\Omega$	<u>3</u> /					
See footnotes at end of ta	ıble.							
	TANDARD RCUIT DRA	WING		IZE A			596	2-89932
MICROCI		COLUMBUS	L		EVISION LEV			

查询"5962R8993201	V2A"供应的	D Conditi	ons <u>1</u> /					
Test	Symbol	-55°C # T, V _S = \pm 15 V, I _R unless otherw	₄ #+125°C _{REF} = 2 mA	Group A subgroups	Device type	Ľ	imits	Unit
						Min	Max	
^D ower supply sensitivity	PSSI _{FS+}	V+ = 4.5 V to V- = -18 V, I _{RE}		1, 2, 3	All		±0.01	%∆l ₀
			<u>3</u> /					%ΔV+
	PSSI _{FS-}	V- = -4.5 V to V+ = 18 V, I _{RE}					±0.01	
Reference bias current	I _{VREF-}	<u>3</u> /	_	1, 2, 3	All	0	-3	μA
_ogic input levels	VIL	Logic "0", V _{LC}	= 0 V	1, 2, 3	All		0.8	V
			M,D,P,L,R	1	_		0.8	-
	V _{IH}	Logic "1", V _{LC}	= 0 V	1, 2, 3	-	2		v
			M,D,P,L,R	1	-	2		
_ogic input current	IIL	V _{IN} = -10 V, V	LC = 0 V	1, 2, 3	All		-10	μA
(each bit)			M,D,P,L,R	1	-		-30	-
	lн	$V_{IN} = 18 V, V_L$	_{.c} = 0 V	1, 2, 3	-		10	μΑ
			M,D,P,L,R	1	-		10	-
_ogic input swing	V _{IS}	I _{FR} = 1.94 mA I _{FR} = 2.04 mA <u>3</u> /		1, 2, 3	All	-10	+18	V
Monotonicity		<u>3</u> /		1, 2, 3	All	8		Bits
Nonlinearity	NL			1, 2, 3	01		±0.19	%FS
			M,D,P,L,R	1	-		±0.45	-
				1, 2, 3	02		±0.1	-
			M,D,P,L,R	1	-		±0.35	-
See footnotes at end of tab	ble.							
	ANDARD		S	GIZE A			590	62-8993
MICROCII	RCUIT DRA	WING	I	~				

查询"5962R8993201V	 /2A"供应ī	든 I. <u>Electrical performance char</u> a	<u>acteristics</u> - Co	ntinued.			
Test	Symbol	$\begin{array}{c} \mbox{Conditions} & \underline{1}/\\ -55^{\circ}\mbox{C} T_{A} \#+125^{\circ}\mbox{C}\\ \mbox{V}_{S} = \pm 15 V, I_{REF} = 2 mA\\ \mbox{unless otherwise specified} \end{array}$	Group A subgroups	Device type	Li	imits	Unit
					Min	Max	
Power dissipation <u>4</u> /	P _D	$V_{\rm S} = \pm 5 \text{ V}, \text{ I}_{\rm REF} = 1 \text{ mA}$ <u>3</u> /	1, 2, 3	All		48	mW
		$V_{S} = +5 V$, -15 V, $I_{REF} = 2 mA $ <u>3</u> /	1			136	1
		$V_{\rm S} = \pm 15$ V, $I_{\rm REF} = 2$ mA $\underline{3}/$	1			174	1
Full scale tempco	TCI _{FS}	<u>3</u> /	8	All		±80	ppm/°C
Settling time	ts	To ±1/2 LSB, T _A = +25°C <u>3</u> /	9	01		150	ns
				02		135	1
Reference input slew rate	dl/dt		9	All	4		mA/μs
Propagation delay all bits switched	t _{PLH}	Low to high transition, $V_L = 0.7 V$, f = 50 MHz minimum <u>3</u> /	9, 10, 11	All		60	ns
	t _{PHL}	High to low transition, $V_L = 2.7 V$, f = 50 MHz minimum <u>3</u> /				60	

1/ Devices supplied to this drawing have been characterized through all levels M, D, P, L, R of irradiation. However, this device is only tested at the "R" level. Pre and Post irradiation values are identical unless otherwise specified in table I.

2/ When the device is used in an un-biased state at high temperature only, and subsequently biased, the device supply currents may rise 30% above specification for as long as 30 seconds.

3/ This parameter is not tested post-irradiation.

4/ Power dissipation limits are guaranteed by supply current testing.

3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-HDBK-103. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

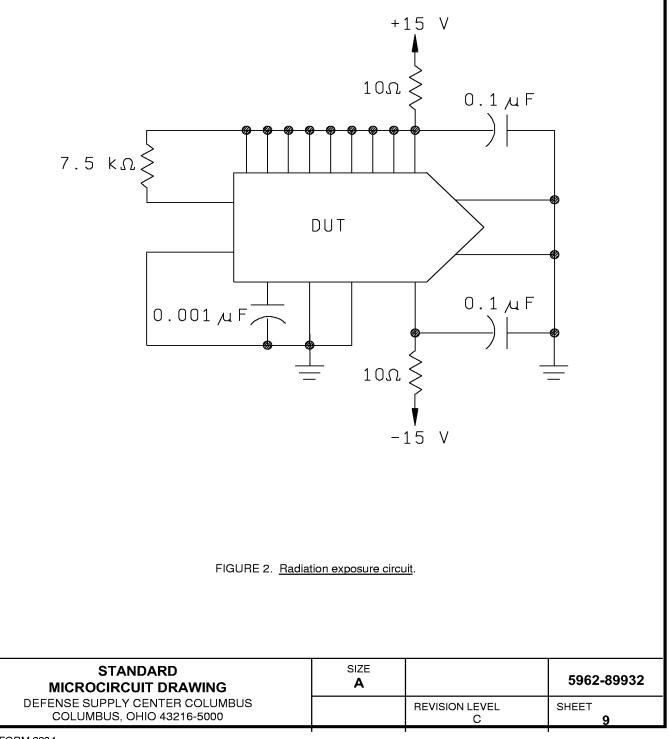
STANDARD	SIZE		5962-89932
MICROCIRCUIT DRAWING	A		J902-09932
DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000		REVISION LEVEL C	SHEET 7

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Device types	01 a	nd 02		
Case outlines	E and F	2		
Terminal number	Termina	al symbol		
1	V _{LC}	NC		
2	Ιουτ	V _{LC}		
3	V-	lout		
4	lout	V-		
5	MSB B1	lout		
6	B2	NC		
7	B3	B1 (MSB)		
8	B4	B2		
9	B5	ВЗ		
10	B6	B4		
11	B7	NC		
12	B8 LSB	B5		
13	V+	B6		
14	V_{REF+}	B7		
15	V_{REF}	B8 (LSB)		
16	COMP	NC		
17		V+		
18		V_{REF} +		
19		V_{REF}		
20		COMP		

FIGURE 1. Terminal connections.

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3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 <u>Notification of change for device class M</u>. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-973.

3.9 <u>Verification and review for device class M</u>. For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 56 (see MIL-PRF-38535, appendix A).

4. QUALITY ASSURANCE PROVISIONS

4.1 <u>Sampling and inspection</u>. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
 - (2) $T_A = +125EC$, minimum.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.

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TABLE IIA. Electrical test requirements.

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	Test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	Subgroups (in accordance with MIL-PRF-38535, table III)	
		Device class M	Device class Q	Device class V
	electrical neters (see 4.2)	1	1	1
	ectrical neters (see 4.2)	1, 2, 3 <u>1</u> /	1, 2, 3 <u>1</u> /	1, 2, 3 <u>1</u> / <u>2</u> /
Group require	A test ements (see 4.4)	1, 2, 3, 8, 9, 10, 11	1, 2, 3, 8, 9, 10, 11	1, 2, 3, 8, 9, 10, 11
	C end-point electrical neters (see 4.4)	1	1	1 <u>2</u> /
	D end-point electrical neters (see 4.4)	1	1	1
	E end-point electrical neters (see 4.4)			1

 $\underline{1}$ / PDA applies to subgroup 1. $\underline{2}$ / See table IIB for delta measurement parameters.

Table IIB.	. 240 hour burn-in and group C end-point electrical parameters.
------------	-----------------------------------------------------------------

Parameter	Device type	Limit		Delta
		Min	Max	1
I _{FS}	01	1.94 mA	2.04 mA	0.01 mA
	02	1.984 mA	2.000 mA	0.005 mA
	01	1.94 mA	2.04 mA	0.01 mA
IFS				
	02	1.984 mA	2.000 mA	0.005 mA
Izs	01	-2.0 μA	+2.0 μA	0.5 μA
	02	-1.0 μA	+1.0 μA	0.3 μΑ
	01	-2.0 μA	+2.0 μA	0.5 µA
Izs		•		
	02	-1.0 μA	+1.0 μA	0.3 µA

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4.2.2 Additional criteria for device classes Q and V.

- 查询"5%278%9%32%17/2%"(共家)荷动ition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - b. Interim and final electrical test parameters shall be as specified in table IIA herein.
 - c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 <u>Qualification inspection for device classes Q and V</u>. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-PRF-38535 permits alternate in-line control testing. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 4, 5, 6, and 7 in table I, method 5005 of MIL-STD-883 shall be omitted.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
- b. $T_A = +125EC$, minimum.
- c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

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4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3,5 herein). RHA levels for device classes M, Q, and V shall be as specified in MIL-I-38535. End-point electrical parameters sha 姆恩多克尼酸的名称 前近 南

4.4.4.1 <u>Total dose irradiation testing</u>. Total dose irradiation testing shall be performed in accordance with MIL-STD-883 method 1019 condition A and as specified herein.

4.4.4.1.1 <u>Accelerated aging test</u>. Accelerated aging tests shall be performed on all devices requiring a RHA level greater than 5k rads(Si). The post-anneal end-point electrical parameter limits shall be as specified in table I herein and shall be the pre-irradiation end-point electrical parameter limit at 25 C ±5 C. Testing shall be performed at initial qualification and after any design or process changes which may affect the RHA response of the device.

4.4.4.2 <u>Dose rate burnout</u>. When required by the customer test shall be performed on devices, SEC, or approved test structures at technology qualifications and after any design or process changes which may effect the RHA capability of the process. Dose rate burnout shall be performed in accordance with test method 1023 of MIL-STD-883 and as specified herein.

5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.

6.3 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0525.

6.4 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0674.

6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 <u>Sources of supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.

6.6.2 <u>Approved sources of supply for device class M</u>. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-89932
DEFENSE SUPPLY CENTER COLUMBUS		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43216-5000		C	13

查询"5962R8993201V2A"供应商

DATE: 99-07-30

Approved sources of supply for SMD 5962-89932 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-89932012A	24355	DAC08RC
5962R8993201VEA	24355	DAC08Q/QMLR
5962R8993201V2A	24355	DAC08RC/QMLR
5962R8993201VFA	24355	DAC08F/QMLR
5962R8993202VEA	24355	DAC08AQ/QMLR
5962R8993202V2A	24355	DAC08ARC/QMLR
5962R8993202VFA	24355	DAC08AF/QMLR

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

Vendor CAGE <u>number</u>

24355

Vendor name and address

Analog Devices RT 1 Industrial Park PO Box 9106 Norwood, MA 02062 Point of contact: 1500 Space Park Drive PO Box 58020 Santa Clara, CA 95052-8020

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.